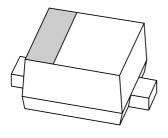
### DISCRETE SEMICONDUCTORS

# DATA SHEET



## 1PS79SB31 Schottky barrier diode

**Product specification** 

2002 Jan 11





### Schottky barrier diode

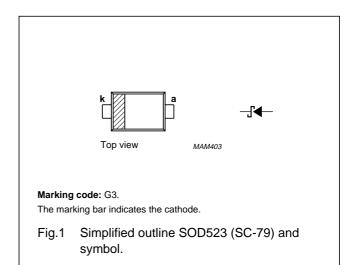
### 1PS79SB31

#### **FEATURES**

- Very low forward voltage
- · Guard ring protected
- Ultra small SMD package.

### **APPLICATIONS**

- Ultra high-speed switching
- Voltage clamping
- · Protection circuits
- Low current rectification
- Low power consumption applications (e.g. hand-held devices).



### **DESCRIPTION**

Planar Schottky barrier diode in a SOD523 (SC-79) ultra small SMD plastic package.

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>R</sub>	continuous reverse voltage		_	30	V
I <sub>F</sub>	continuous forward current		_	200	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ s; } \delta \le 0.5$	_	300	mA
I <sub>FSM</sub>	non-repetitive peak forward current	t = 8.3 ms half sine wave; JEDEC method	_	1000	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		_	125	°C
T <sub>amb</sub>	operating ambient temperature		-65	+125	°C

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### **ELECTRICAL CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>F</sub>	forward voltage	see Fig.2;			
		I <sub>F</sub> = 0.1 mA	130	190	mV
		I <sub>F</sub> = 1 mA	190	250	mV
		I <sub>F</sub> = 10 mA	255	300	mV
		I <sub>F</sub> = 100 mA	355	410	mV
		I <sub>F</sub> = 200 mA	420	500	mV
I <sub>R</sub>	continuous reverse current	V <sub>R</sub> = 10 V; note 1; see Fig.3	2.5	30	μΑ
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V; f = 1 MHz; see Fig.4	20	25	pF

### Note

1. Pulse test:  $t_p$  = 300  $\mu$ s;  $\delta$  = 0.02.

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	450	K/W

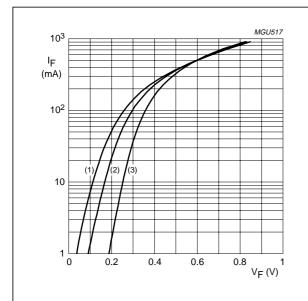
### Note

1. Refer to SC-79 (SOD523) standard mounting conditions.

### Schottky barrier diode

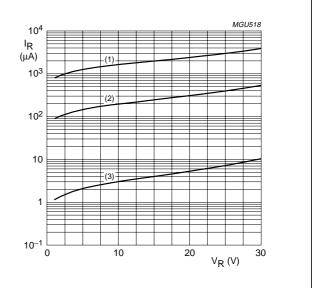
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### **GRAPHICAL DATA**



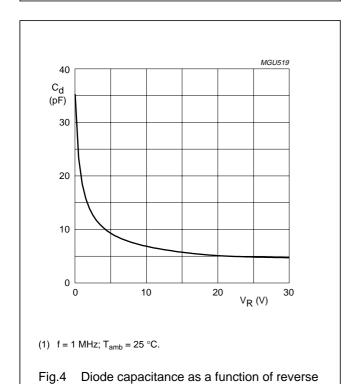
- (1)  $T_{amb} = 125$  °C.
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .

Fig.2 Forward current as a function of forward voltage; typical values.



- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .

Fig.3 Reverse current as a function of reverse voltage; typical values.



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voltage; typical values.

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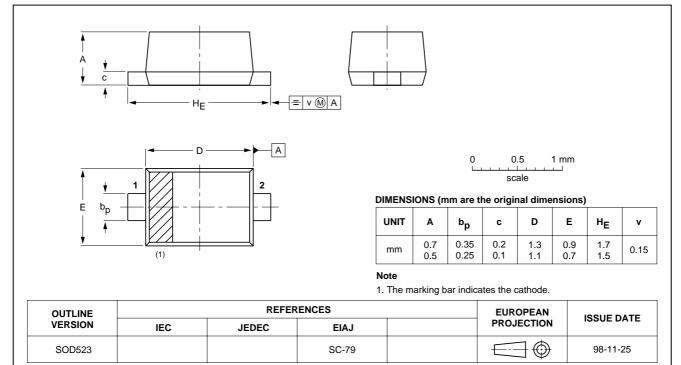
### Schottky barrier diode

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### **PACKAGE OUTLINE**

### Plastic surface mounted package; 2 leads

**SOD523** 



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### Schottky barrier diode

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#### **DATA SHEET STATUS**

DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
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### Schottky barrier diode

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NOTES

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